NSN 5961-01-293-7096

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-293-7096 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.185 inches **Terminal Length:** Between 1.000 inches and 1.300 inches **Overall Diameter:** Between 0.085 inches and 0.140 inches **Mounting Method:** Terminal **Terminal Circle Diameter:** Between 0.026 inches and 0.033 inches **Features Provided:** Quality assurance level txv **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 9.00 breakover voltage, instantaneous and 11.00 breakover voltage, instantaneous **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 125.00 milliamperes drain current peak and 20.00 microamperes forward current, average peak **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/516 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: